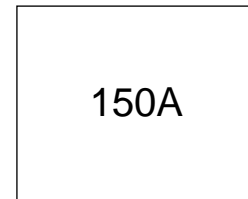


FAST RECOVERY DIODES

Stud Version

Features

- High power FAST recovery diode series
- 1.0 to 1.5 μ s recovery time
- High voltage ratings up to 1600V
- High current capability
- Optimized turn on and turn off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Compression bonded encapsulation
- Stud version JEDEC DO-30
- Maximum junction temperature 125°C

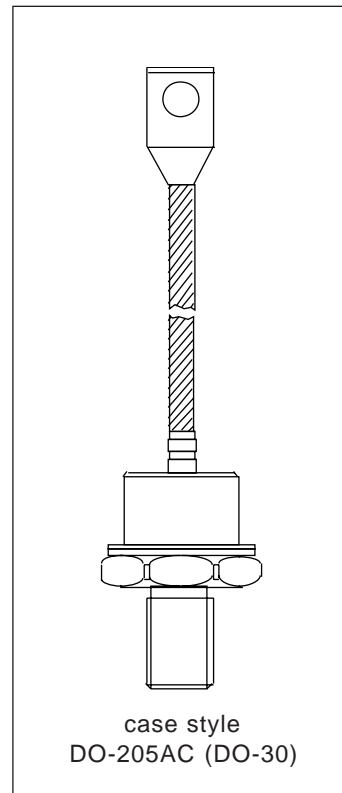


Typical Applications

- Snubber diode for GTO
- High voltage free-wheeling diode
- Fast recovery rectifier applications

Major Ratings and Characteristics

Parameters	SD153N/R	Units
$I_{F(AV)}$	150	A
@ T_C	85	°C
$I_{F(RMS)}$	235	A
I_{FSM} @ 50Hz	4280	A
@ 60Hz	4480	A
I^2t @ 50Hz	92	KA ² s
@ 60Hz	84	KA ² s
V_{RRM} range	400 to 1600	V
t_{rr} range	1.0 to 1.5	μ s
@ T_J	25	°C
T_J	- 40 to 125	°C



ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V _{RRM} max. repetitive peak and off-state voltage V	V _{RSM} , maximum non-repetitive peak voltage V	I _{RRM} max. T _J = 125°C mA
SD153N/R..S10	04	400	500	35
	08	800	900	
	10	1000	1100	
SD153N/R..S15	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

Forward Conduction

Parameter	SD153N/R	Units	Conditions
I _{F(AV)} Max. average forward current @ Case temperature	150	A	180° conduction, half sine wave.
	85	°C	
I _{F(RMS)} Max. RMS current	235	A	DC @ 74°C case temperature
I _{FSM} Max. peak, one-cycle non-repetitive forward current	4280	A	t = 10ms No voltage
	4480		t = 8.3ms reapplied
	3600		t = 10ms 100% V _{RRM}
	3770		t = 8.3ms reapplied
I ² t Maximum I ² t for fusing	92	KA ² s	t = 10ms No voltage
	84		t = 8.3ms reapplied
	65		t = 10ms 100% V _{RRM}
	59		t = 8.3ms reapplied
I ² √t Maximum I ² √t for fusing	916	KA ² √s	t = 0.1 to 10ms, no voltage reapplied
V _{F(TO)1} Low level of threshold voltage	1.00	V	(16.7% × π × I _{F(AV)} < I < π × I _{F(AV)}), T _J = T _J max.
V _{F(TO)2} High level of threshold voltage	1.46		(I > π × I _{F(AV)}), T _J = T _J max.
r _{f1} Low level of forward slope resistance	1.35	mΩ	(16.7% × π × I _{F(AV)} < I < π × I _{F(AV)}), T _J = T _J max.
r _{f2} High level of forward slope resistance	0.52		(I > π × I _{F(AV)}), T _J = T _J max.
V _{FM} Max. forward voltage	1.55	V	I _{pk} = 470 A, T _J = 25°C, t _p = 400 μs square pulse

Recovery Characteristics

Code	T _J = 25°C typical t _{rr} @ 25% I _{RRM} (μs)	Test conditions			Max. values @ T _J = 125°C			
		I _{pk} Square Pulse (A)	di/dt (A/μs)	V _r (V)	t _{rr} @ 25% I _{RRM} (μs)	Q _{rr} (μC)	I _{rr} (A)	
S10	1.0	350	25	-30	1.6	21	27	
S15	1.5				2.3	61	37	

Thermal and Mechanical Specification

Parameter	SD153N/R	Units	Conditions
T _J Max. operating temperature range	-40 to 125	°C	
T _{stg} Max. storage temperature range	-40 to 150		
R _{thJC} Max. thermal resistance, junction to case	0.16	K/W	DC operation
R _{thCS} Max. thermal resistance, case to heatsink	0.10		Mounting surface, smooth, flat and greased
T Mounting torque ± 10%	15.5	Nm	Not lubricated threads
	13.5		Lubricated threads
wt Approximate weight	120	g	
Case style	DO-205AC (DO-30)		See Outline Table

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.011	0.012	K/W	T _J = T _J max.
120°	0.016	0.019		
90°	0.021	0.023		
60°	0.029	0.030		
30°	0.041	0.041		

Ordering Information Table

Device Code

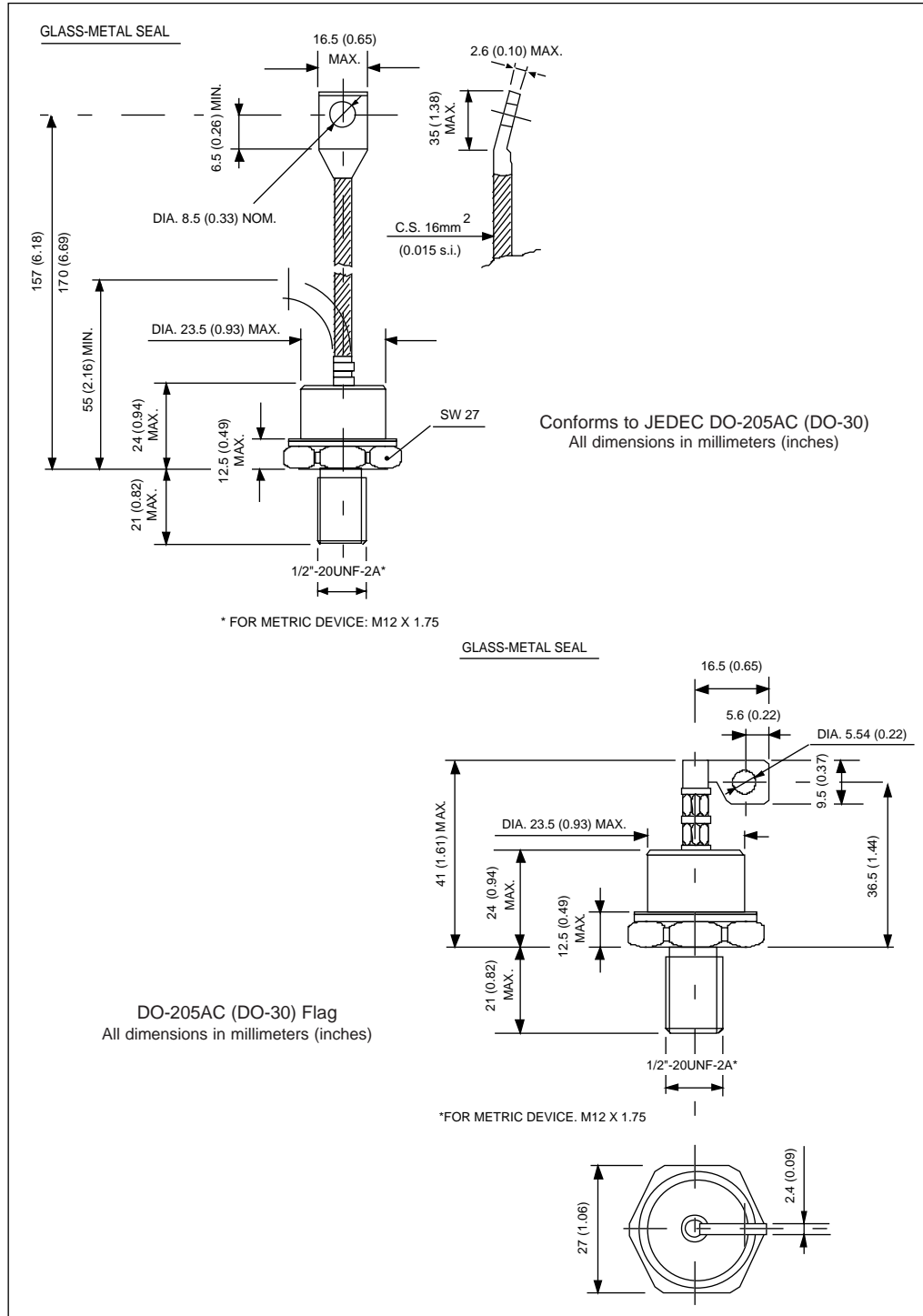
SD	15	3	R	16	S15	P	B	V
①	②	③	④	⑤	⑥	⑦	⑧	⑨

- 1** - Diode
- 2** - Essential part number
- 3** - 3 = Fast recovery
- 4** - N = Stud Normal Polarity (Cathode to Stud)
R = Stud Reverse Polarity (Anode to Stud)
- 5** - Voltage code: Code x 100 = V_{RRM} (see Voltage Ratings table)
- 6** - t_{rr} code (see Recovery Characteristics table)
- 7** - P = Stud base DO-205AC (DO-30) 1/2" 20UNF-2A
M = Stud base DO-205AC (DO-30) M12 X 1.75
- 8** - B = Flag top terminals (for Cathode/ Anode Leads)
S = Isolated lead with silicone sleeve
(Red = Reverse Polarity; Blue = Normal Polarity)
None = Not isolated lead
- 9** - V = Glass-metal seal

SD153N/R Series

Bulletin I2063 rev. A 09/94

Outline Table



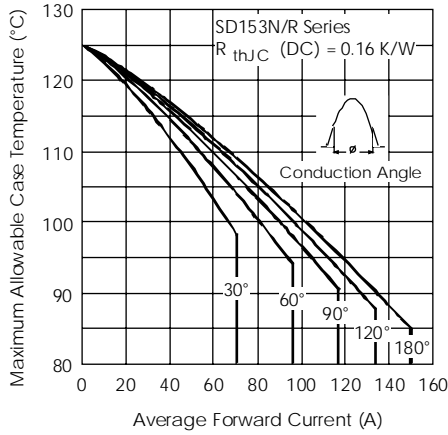


Fig. 1 - Current Ratings Characteristics

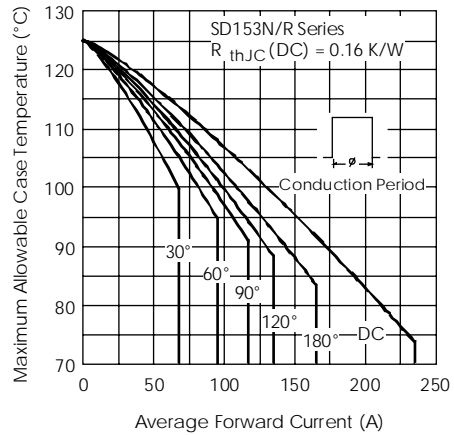


Fig. 2 - Current Ratings Characteristics

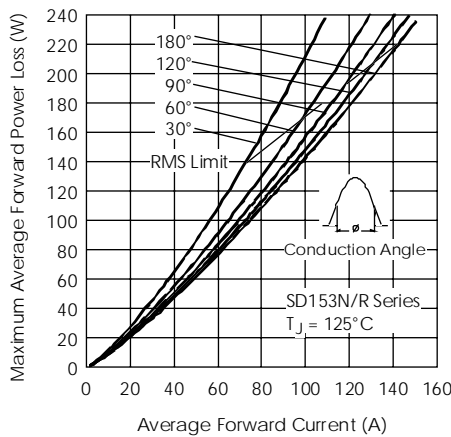


Fig. 3 - Forward Power Loss Characteristics

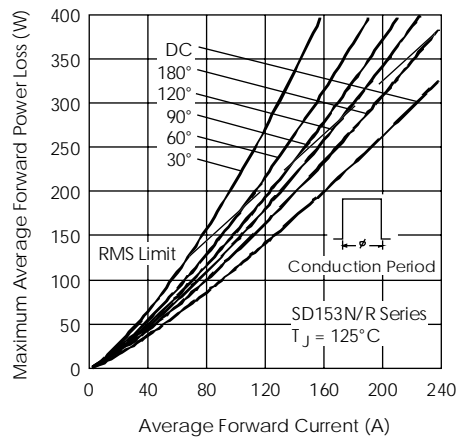


Fig. 4 - Forward Power Loss Characteristics

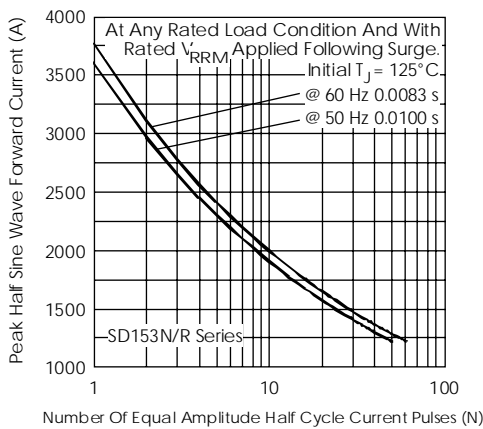


Fig. 5 - Maximum Non-repetitive Surge Current

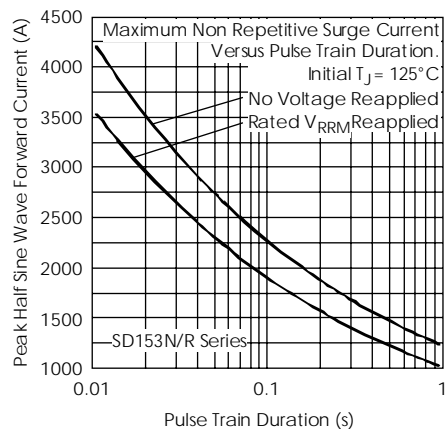


Fig. 6 - Maximum Non-repetitive Surge Current

SD153N/R Series

Bulletin I2063 rev. A 09/94

International
IRF Rectifier

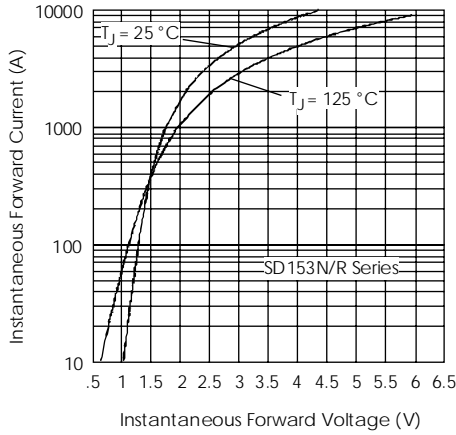


Fig. 7 - Forward Voltage Drop Characteristics

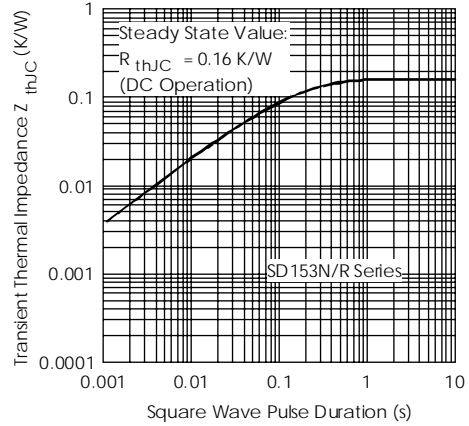


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic

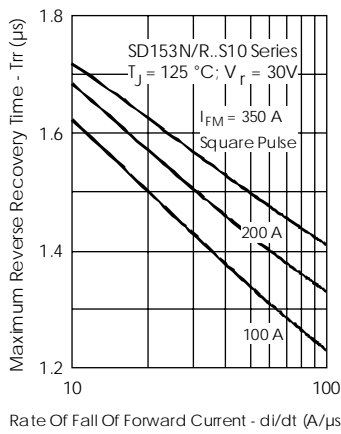


Fig. 9 - Recovery Time Characteristics

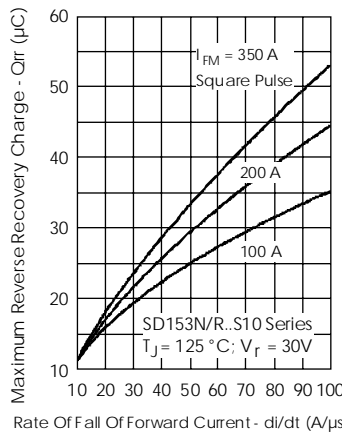


Fig. 10 - Recovery Charge Characteristics

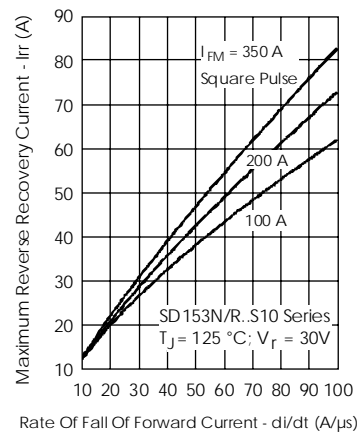


Fig. 11 - Recovery Current Characteristics

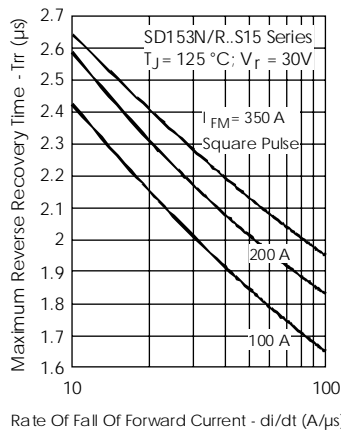


Fig. 12 - Recovery Time Characteristics

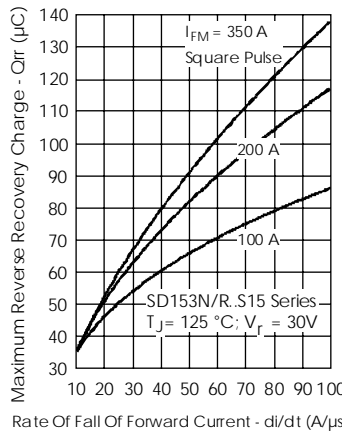


Fig. 13 - Recovery Charge Characteristics

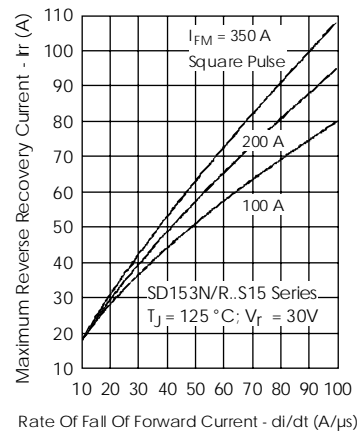


Fig. 14 - Recovery Current Characteristics

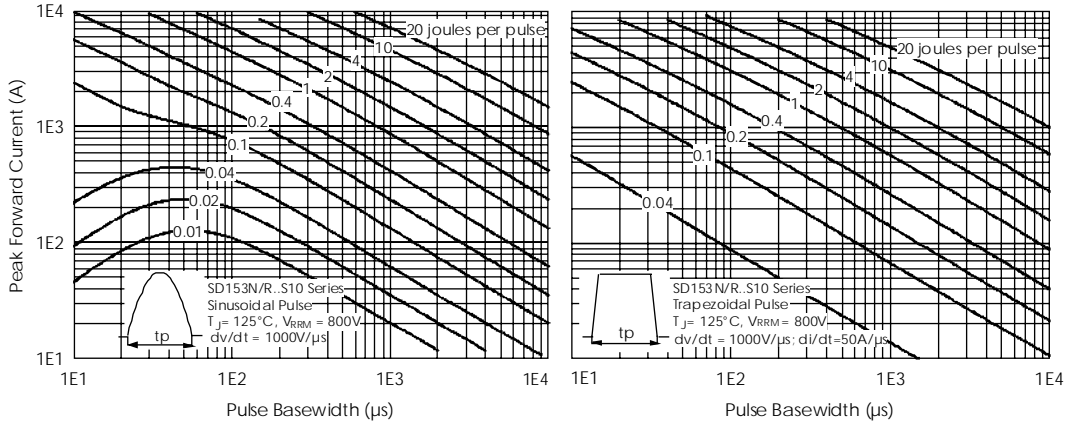


Fig. 15 - Maximum Total Energy Loss Per Pulse Characteristics

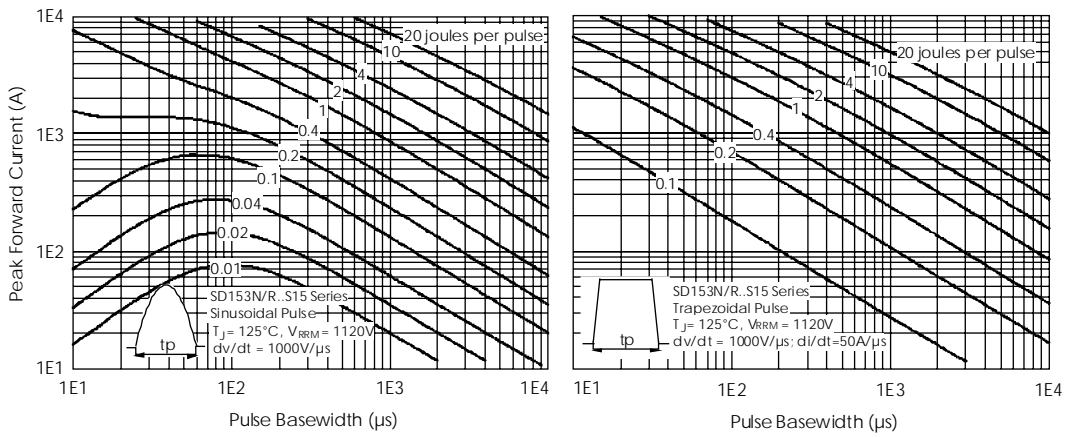


Fig. 16 - Maximum Total Energy Loss Per Pulse Characteristics

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